RENESAS

3.3V CMOS 16-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

IDT74ALVC162244

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical $t_{SK(o)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- V_{CC} = 3.3V ± 0.3V, Normal Range
- V_{CC} = 2.7V to 3.6V, Extended Range
- V_{CC} = 2.5V ± 0.2V
- CMOS power levels (0.4μ W typ. static)
- Rail-to-Rail output swing for increased noise margin
- Available in TSSOP package

DRIVE FEATURES:

- Balanced Output Drivers: ±12mA
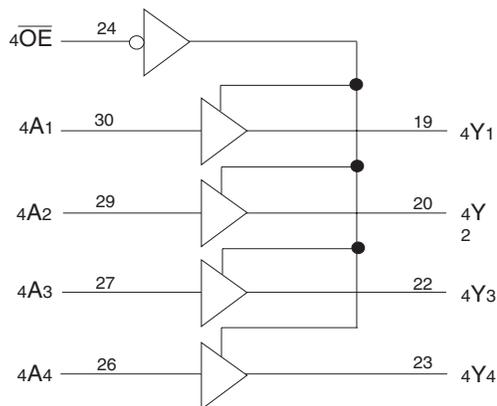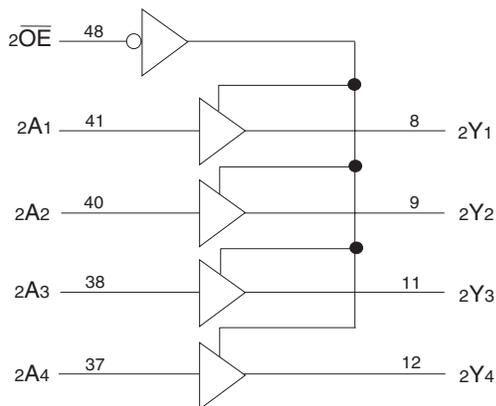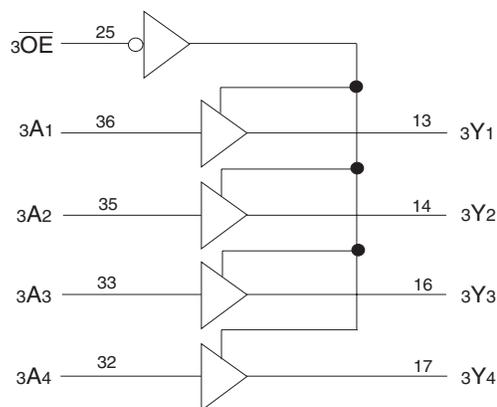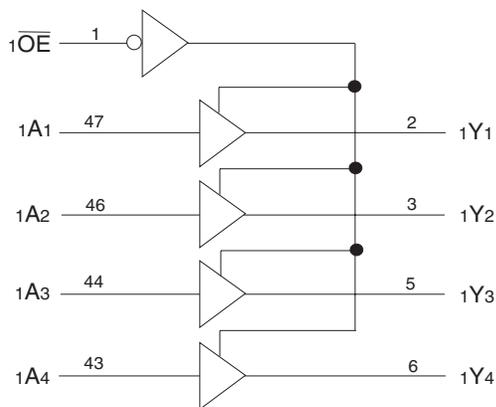- Low switching noise

DESCRIPTION:

This 16-bit buffer/driver is built using advanced dual metal CMOS technology. The ALVC162244 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. It provides true outputs and symmetrical active-low output-enable ($\overline{OE}$) inputs.

The ALVC162244 has series resistors in the device output structure which will significantly reduce line noise when used with light loads. This driver has been designed to drive ±12mA at the designated threshold levels.
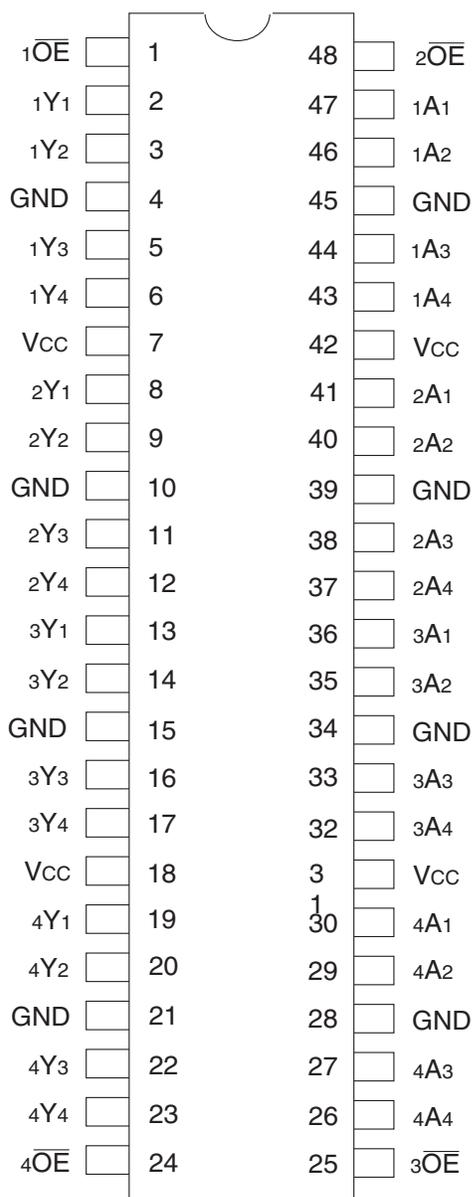
APPLICATIONS:

- 3.3V high speed systems
- 3.3V and lower voltage computing systems

FUNCTIONAL BLOCK DIAGRAM

INDUSTRIAL TEMPERATURE RANGE

JUNE 2009

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DSC-4560/6

PIN CONFIGURATION

1$\overline{OE}$	1	48	2$\overline{OE}$
1Y1	2	47	1A1
1Y2	3	46	1A2
GND	4	45	GND
1Y3	5	44	1A3
1Y4	6	43	1A4
Vcc	7	42	Vcc
2Y1	8	41	2A1
2Y2	9	40	2A2
GND	10	39	GND
2Y3	11	38	2A3
2Y4	12	37	2A4
3Y1	13	36	3A1
3Y2	14	35	3A2
GND	15	34	GND
3Y3	16	33	3A3
3Y4	17	32	3A4
Vcc	18	31	Vcc
4Y1	19	30	4A1
4Y2	20	29	4A2
GND	21	28	GND
4Y3	22	27	4A3
4Y4	23	26	4A4
4$\overline{OE}$	24	25	3$\overline{OE}$

TSSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS[1]

Symbol	Description	Max	Unit
V$_{TERM}$[2]	Terminal Voltage with Respect to GND	–0.5 to +4.6	V
V$_{TERM}$[3]	Terminal Voltage with Respect to GND	–0.5 to Vcc+0.5	V
T$_{STG}$	Storage Temperature	–65 to +150	°C
I$_{OUT}$	DC Output Current	–50 to +50	mA
I$_{IK}$	Continuous Clamp Current, V$_I$ < 0 or V$_I$ > Vcc	±50	mA
I$_{OK}$	Continuous Clamp Current, V$_O$ < 0	–50	mA
I$_{CC}$ I$_{SS}$	Continuous Current through each Vcc or GND	±100	mA

NOTES:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Vcc terminals.
3. All terminals except Vcc.

CAPACITANCE (T$_A$ = +25°C, F = 1.0MHz)

Symbol	Parameter[1]	Conditions	Typ.	Max.	Unit
C$_{IN}$	Input Capacitance	V$_{IN}$ = 0V	5	7	pF
C$_{OUT}$	Output Capacitance	V$_{OUT}$ = 0V	7	9	pF
C$_{OUT}$	I/O Port Capacitance	V$_{IN}$ = 0V	7	9	pF

NOTE:
1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description
x$\overline{OE}$	3-State Output Enable Inputs (Active LOW)
xAx	Data Inputs
xYx	3-State Outputs

FUNCTION TABLE (EACH 4-BIT BUFFER)[1]

Inputs		Outputs
x$\overline{OE}$	xAx	xYx
L	H	H
L	L	L
H	X	Z

NOTE:
1. H = HIGH Voltage Level
   X = Don't Care
   L = LOW Voltage Level
   Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:
Operating Condition: T_A = –40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ.[1]	Max.	Unit
V_{IH}	Input HIGH Voltage Level	V_{CC} = 2.3V to 2.7V		1.7	—	—	V
		V_{CC} = 2.7V to 3.6V		2	—	—	
V_{IL}	Input LOW Voltage Level	V_{CC} = 2.3V to 2.7V		—	—	0.7	V
		V_{CC} = 2.7V to 3.6V		—	—	0.8	
I_{IH}	Input HIGH Current	V_{CC} = 3.6V	V_I = V_{CC}	—	—	±5	µA
I_{IL}	Input LOW Current	V_{CC} = 3.6V	V_I = GND	—	—	±5	µA
I_{OZH}	High Impedance Output Current	V_{CC} = 3.6V	V_O = V_{CC}	—	—	±10	µA
I_{OZL}	(3-State Output pins)		V_O = GND	—	—	±10	
V_{IK}	Clamp Diode Voltage	V_{CC} = 2.3V, I_{IN} = –18mA		—	–0.7	–1.2	V
V_H	Input Hysteresis	V_{CC} = 3.3V		—	100	—	mV
I_{CCL} I_{CCH} I_{CCZ}	Quiescent Power Supply Current	V_{CC} = 3.6V V_{IN} = GND or V_{CC}		—	0.1	40	µA
ΔI_{CC}	Quiescent Power Supply Current Variation	One input at V_{CC} - 0.6V, other inputs at V_{CC} or GND		—	—	750	µA

NOTE:
1. Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions[1]		Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = 2.3V to 3.6V	I_{OH} = – 0.1mA	V_{CC} – 0.2	—	V
		V_{CC} = 2.3V	I_{OH} = – 4mA	1.9	—	
			I_{OH} = – 6mA	1.7	—	
		V_{CC} = 2.7V	I_{OH} = – 4mA	2.2	—	
			I_{OH} = – 8mA	2	—	
		V_{CC} = 3V	I_{OH} = – 6mA	2.4	—	
			I_{OH} = – 12mA	2	—	
V_{OL}	Output LOW Voltage	V_{CC} = 2.3V to 3.6V	I_{OL} = 0.1mA	—	0.2	V
		V_{CC} = 2.3V	I_{OL} = 4mA	—	0.4	
			I_{OL} = 6mA	—	0.55	
		V_{CC} = 2.7V	I_{OL} = 4mA	—	0.4	
			I_{OL} = 8mA	—	0.6	
		V_{CC} = 3V	I_{OL} = 6mA	—	0.55	
			I_{OL} = 12mA	—	0.8	

NOTE:
1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range. T_A = – 40°C to + 85°C.

OPERATING CHARACTERISTICS, $T_A = 25°C$

Symbol	Parameter	Test Conditions	$V_{CC} = 2.5V \pm 0.2V$ Typical	$V_{CC} = 3.3V \pm 0.3V$ Typical	Unit
C_{PD}	Power Dissipation Capacitance Outputs enabled	$C_L = 0pF, f = 10Mhz$	16	19	pF
C_{PD}	Power Dissipation Capacitance Outputs disabled		4	5	

SWITCHING CHARACTERISTICS[1]

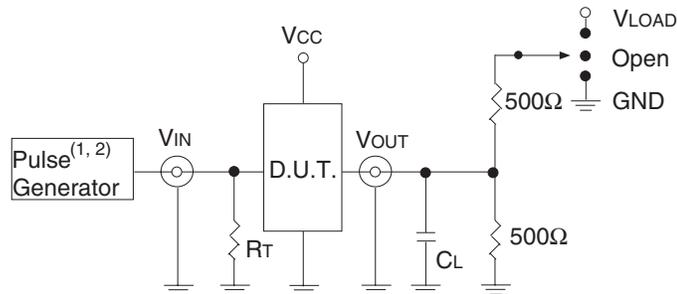| Symbol	Parameter	$V_{CC} = 2.5V \pm 0.2V$ Min.	Max.	$V_{CC} = 2.7V$ Min.	Max.	$V_{CC} = 3.3V \pm 0.3V$ Min.	Max.	Unit
t_{PLH} t_{PHL}	Propagation Delay xAx to xYx	1	4.9	—	4.7	1	4.2	ns
t_{PZH} t_{PZL}	Output Enable Time x$\overline{OE}$ to xYx	1	6.8	—	6.7	1	5.6	ns
t_{PHZ} t_{PLZ}	Output Disable Time x$\overline{OE}$ to xYx	1	6.3	—	5.7	1	5.5	ns
$t_{SK(o)}$	Output Skew[2]	—	—	—	—	—	500	ps

NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. $T_A = -40°C$ to $+85°C$.
2. Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$V_{CC}^{(1)}$ = 3.3V±0.3V	$V_{CC}^{(1)}$ = 2.7V	$V_{CC}^{(2)}$ = 2.5V±0.2V	Unit
V_{LOAD}	6	6	2 x V_{CC}	V
V_{IH}	2.7	2.7	V_{CC}	V
V_T	1.5	1.5	V_{CC} / 2	V
V_{LZ}	300	300	150	mV
V_{HZ}	300	300	150	mV
C_L	50	50	30	pF

Test Circuit for All Outputs

DEFINITIONS:
C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:
1. Pulse Generator for All Pulses: Rate ≤ 1.0MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 1.0MHz; t_F ≤ 2ns; t_R ≤ 2ns.

SWITCH POSITION

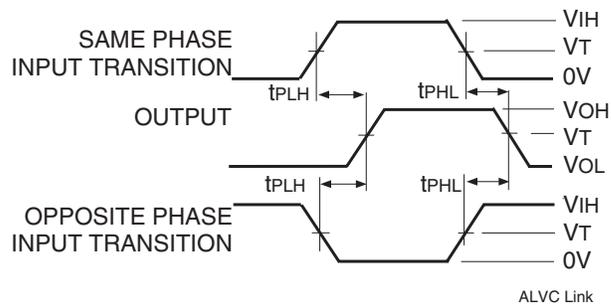| Test	Switch
Open Drain Disable Low Enable Low	V_{LOAD}
Disable High Enable High	GND
All Other Tests	Open
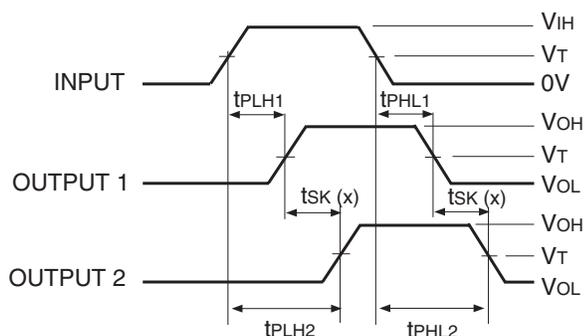
$t_{SK}(x) = |t_{PLH2} - t_{PLH1}|$ or $|t_{PHL2} - t_{PHL1}|$
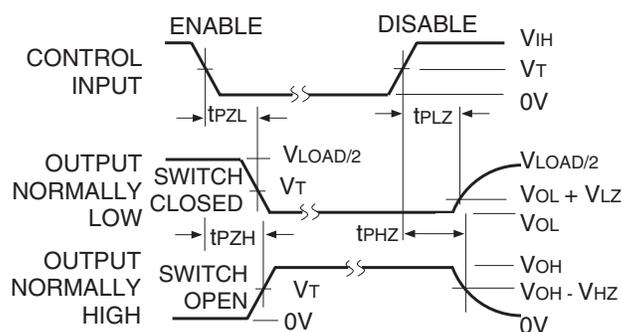
Output Skew - $t_{SK}(x)$

NOTES:
1. For $t_{SK}(o)$ OUTPUT1 and OUTPUT2 are any two outputs.
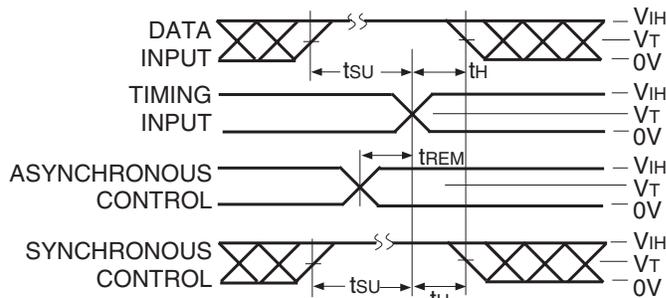2. For $t_{SK}(b)$ OUTPUT1 and OUTPUT2 are in the same bank.
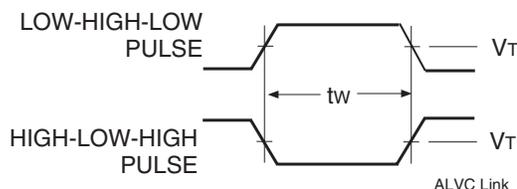

Propagation Delay

Enable and Disable Times

NOTE:
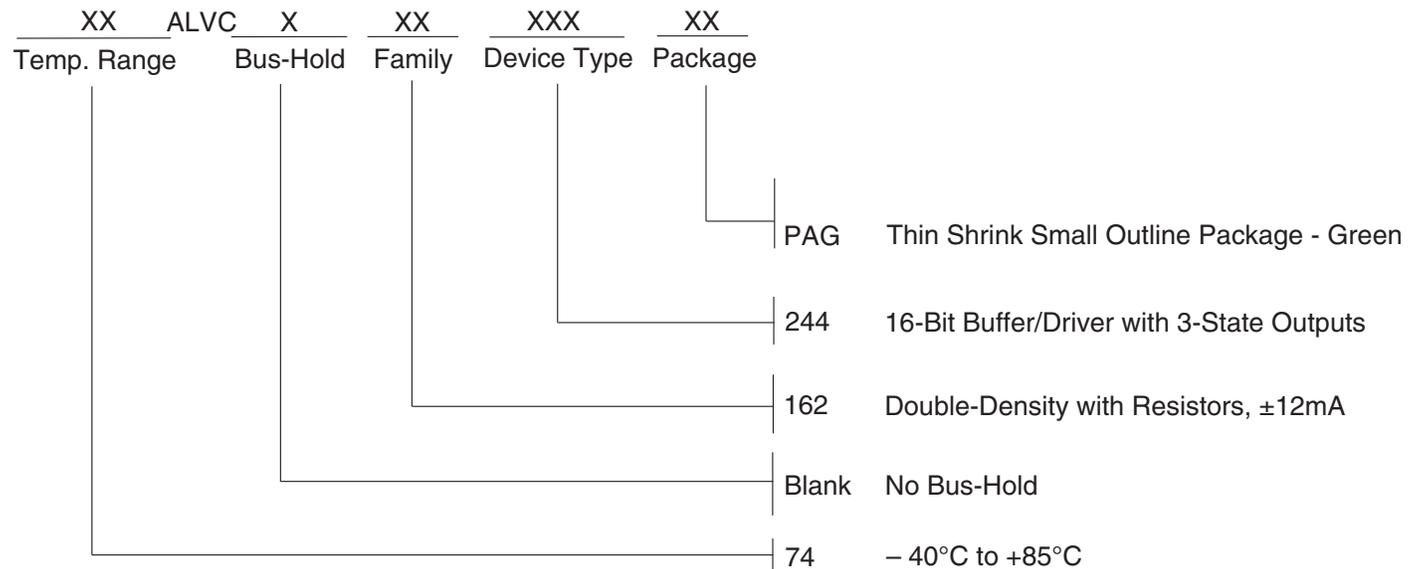1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Set-up, Hold, and Release Times

Pulse Width

ORDERING INFORMATION

XX	ALVC	X	XX	XXX	XX
Temp. Range		Bus-Hold	Family	Device Type	Package

PAG — Thin Shrink Small Outline Package - Green

244 — 16-Bit Buffer/Driver with 3-State Outputs

162 — Double-Density with Resistors, ±12mA

Blank — No Bus-Hold

74 — – 40°C to +85°C

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Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

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